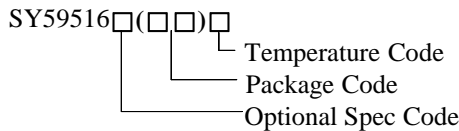


## General Description

SY59516 is the high side LLC controller integrated with a 500V MOSFET, it is used in charge pump PFC application. High PF is achieved by inherent PFC function and low LED current ripple is achieved by LLC topology. Single stage structure and primary side regulation save BOM cost a lot. Meanwhile, LLC topology improves efficiency and EMI.

It should work with SY59515, which is the low side LLC controller integrated with a 500V MOSFET.

## Ordering Information



Ordering Number	Package type	Note
SY59516FAC	SO8	----

## Features

- Integrated 500V MOSFET
- Charge Pump PFC LLC Topology with Low BOM Cost
- PF>0.95, THD<20%
- Primary Side I<sub>LED</sub> Regulation and Less than 2% I<sub>LED</sub> Ripple
- Over Current Protection (OCP), Over Temperature Protection (OTP), Thermal Fold Back (TFB), Adaptive Prevent Capacitive Mode Function
- Zero Voltage Overshoot on Resonant Capacitor at Startup
- Compact Package: SO8

## Applications

- LED Lighting

Recommended operating output power @ V <sub>out</sub> =42V	
Products	198~264Vac
SY59516	42W

## Typical Applications

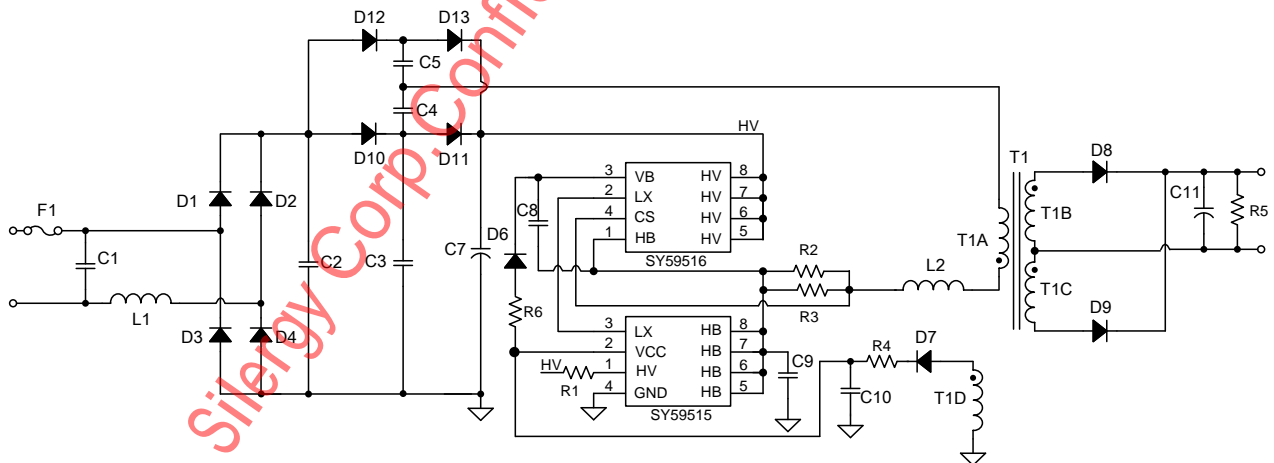


Figure.1a Typical Application

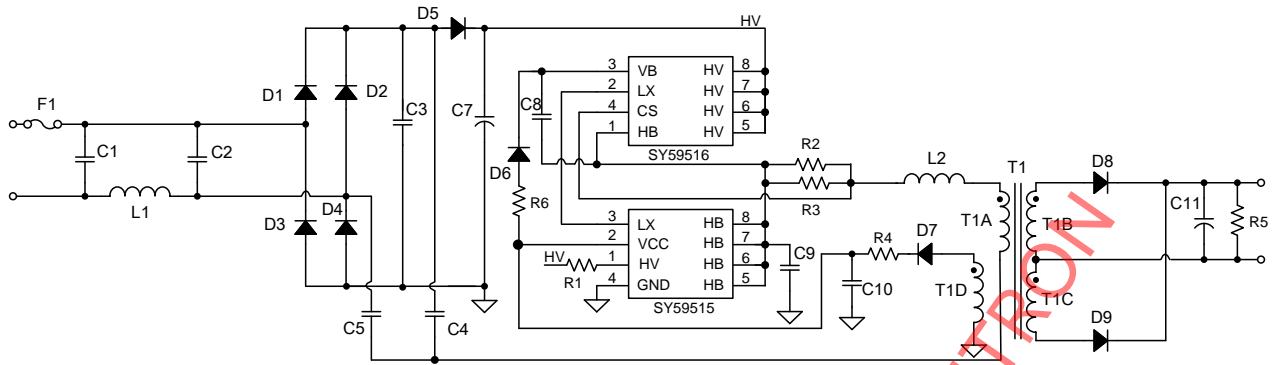


Figure.1b Typical Application

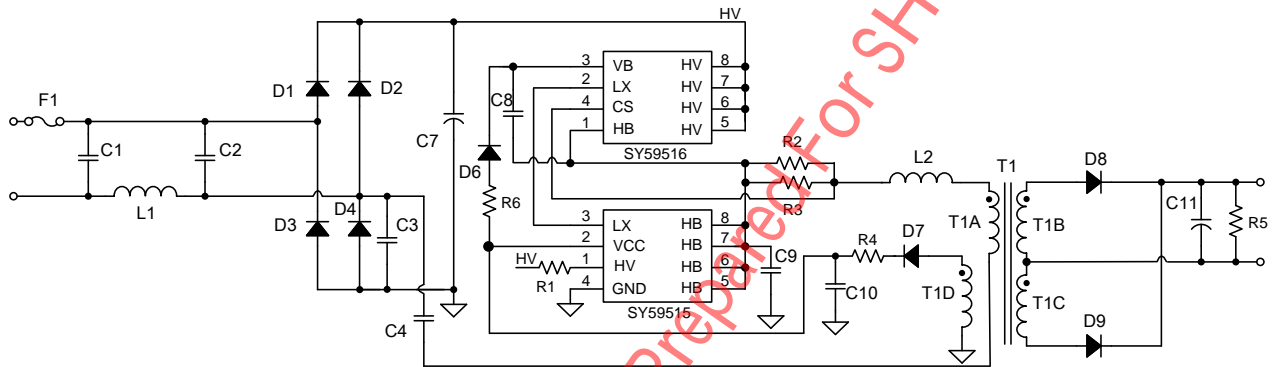


Figure.1c Typical Application

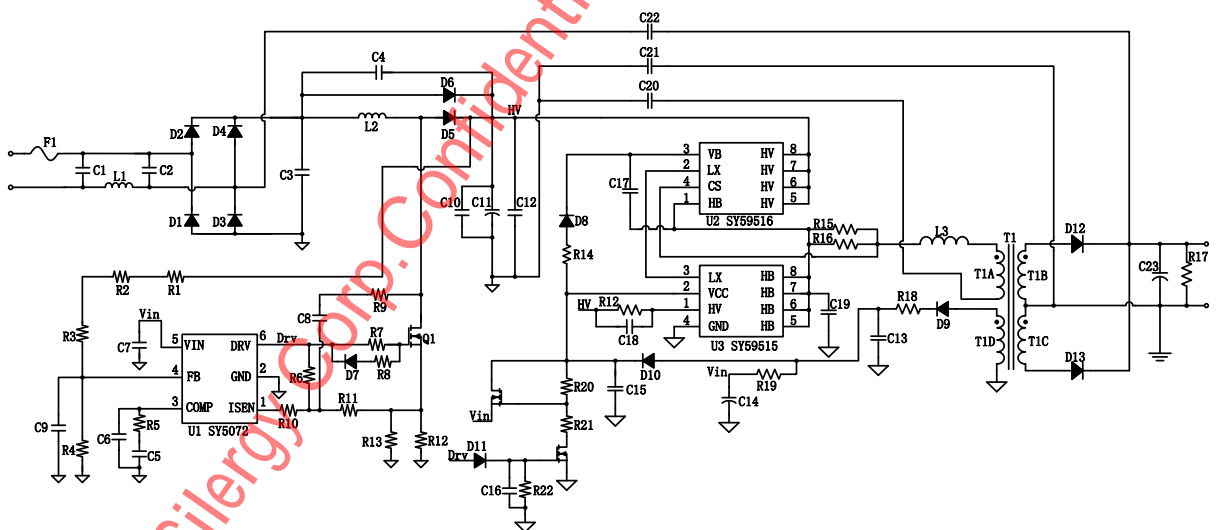
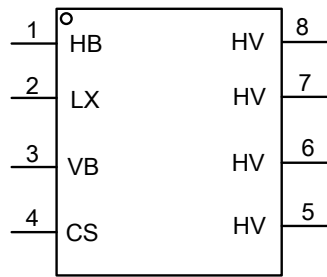


Fig.1d LLC LED Driver with Front End PFC

**Pinout** (top view)



(SO8)

**Top Mark:** CUF xyz (device code: CUF, x=year code, y=week code, z=lot number code)

Pin Name	Pin number	Pin Description
HB	1	High-side floating supply reference ground. Source of high side internal 500V MOSFET.
LX	2	Low side driver control pin. This pin sends the control signal to SY59515 through pulling up LX to VB or pulling down LX to HB
VB	3	High-Side Floating Supply.
CS	4	Primary current sense pin. This pin receives the primary resonant current by sample resistors and realizes OCP function. This pin also provides high side and low side MOSFET switching control through internal loop and adaptive prevent capacitive mode function.
HV	5-8	Drain of internal 500V MOSFET.

**Block Diagram**

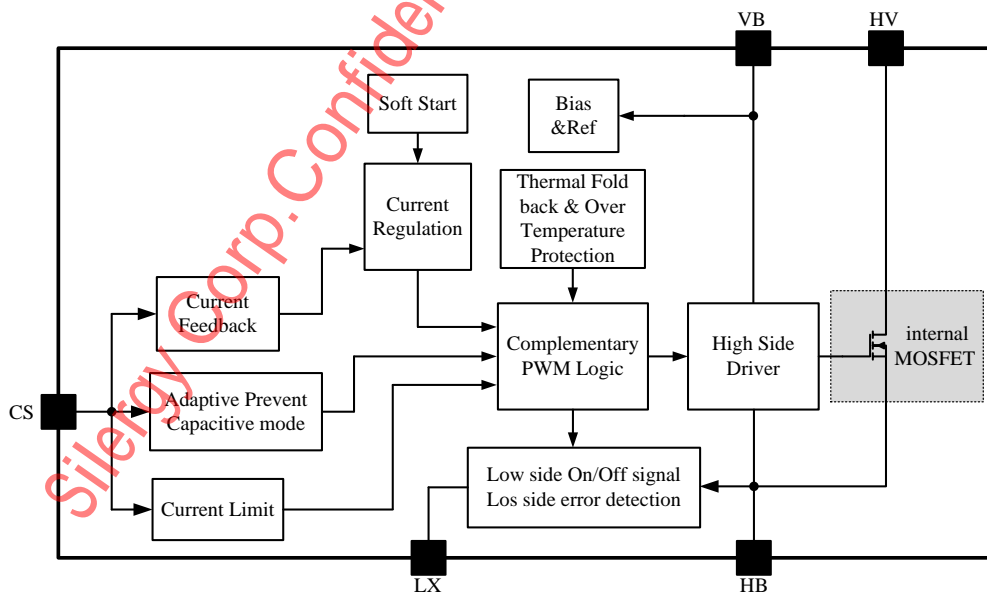


Figure.3 Block Diagram

## Absolute Maximum Ratings (Note 1)

HV	-0.3V ~ 500V
LX	-0.3V ~ 36V
VB	-0.3 ~ 36V
CS	-0.6V ~ 0.6V
Power Dissipation, @ TA = 25°C SO8	1.1W
Package Thermal Resistance (Note 2)	
SO8, $\theta_{JA}$	88°C/W
SO8, $\theta_{JC}$	45°C/W
Maximum Junction Temperature	150°C
Lead Temperature (Soldering, 10 sec.)	260°C
Storage Temperature Range	-65°C to 150°C

## Recommended Operating Conditions

Junction Temperature Range	-40°C to 150°C
Ambient Temperature Range	-40°C to 150°C

## Electrical Characteristics

(V<sub>IN</sub> = 15V, T<sub>A</sub> = 25°C unless otherwise specified)

High Side Controller						
Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Power Supply Section						
VB Turn-on Threshold	V <sub>VB_ON</sub>		20.5	23	25.5	V
VB Turn-off Threshold	V <sub>VB_OFF</sub>		8.7	9.7	10.7	V
Quiescent current	I <sub>Q</sub>	before VB_ON	170	230	290	μA
CS Pin Section						
Current Reference Voltage	V <sub>REF</sub>		147.5	152	156.5	mV
MOSFET Section						
MOSFET R <sub>ds(on)</sub>	R <sub>ds(on)</sub>		0.75	1	1.25	Ω
Breakdown Voltage	V <sub>BV</sub>	V <sub>GS</sub> =0, I <sub>DS</sub> =250μA	500	540		V
Frequency Limit						
Maximum Switching Frequency	F <sub>MAX</sub>		200	230	260	kHz
Minimum Switching Frequency	F <sub>MIN</sub>		25	29	33	kHz
Minimum On Time	T <sub>MIN_ON</sub>		450	575	700	ns
Thermal Section						
Thermal Fold Back Temperature	T <sub>FB</sub>		139	149	159	°C
Thermal Shut Down Temperature	T <sub>SD</sub>			160		°C

**Note 1:** Stresses beyond the “Absolute Maximum Ratings” may cause permanent damage to the device. These are stress ratings only. Functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

**Note 2:**  $\theta_{JA}$  is measured in the natural convection at T<sub>A</sub> = 25°C on a low effective single layer thermal conductivity test board of JEDEC 51-3 thermal measurement standard. Test condition: Device mounted on 2” x 2” FR-4 substrate PCB, 2oz copper, with minimum recommended pad on top layer and thermal vias to bottom layer ground plane.

## Operation

SY59516 is the high side LLC controller integrated with a 500V MOSFET, it is used in charge pump PFC application, which is targeting at LED lighting applications. High PF is achieved by inherent PFC function and low LED current ripple is achieved by LLC topology. Single stage structure and primary side regulation save BOM cost a lot.

SY59516 contains reliable turn on and turn off logic, which can avoid LLC half bridge shoot through and support high switching frequency more than 200kHz. SY59516 also adopts special design to achieve zero voltage overshoot on resonant capacitor at startup. It also uses slope detection function to make sure the valley turn on of MOSFET to achieve higher efficiency.

LLC topology improves efficiency and EMI, furthermore, one external NP0 capacitor can be put between midpoint between LLC half bridge and GND point (or BUS point) to further improve system performance.

SY59516 provides reliable protections including over current protection (OCP), over temperature protection (OTP), thermal fold back (TFB) and so on.

SY59516 is available with SO8 package, and should work with SY59515, which is the low side LLC controller integrated with a 500V MOSFET.

## Applications Information

### Start up

After AC supply or DC BUS is powered on, capacitor  $C_{VCC}$  across VCC and GND pin is charged by internal current source. This current source comes from HV pin, which is connected to  $V_{BUS}$  through one external resistor  $R_{HV\_EXT}$ .

The whole start up process can be divided into 4 sections shown in Fig.3, HO and LO are internal gate of SY59516 and SY59515, respectively.  $t_{STC1}$  is the  $C_{VCC}$  charging up section.  $t_{STD}$  is midpoint HB voltage and HV voltage detecting section, during this time,  $C_{VCC}$  will charge back and forth between  $V_{VCC\_ON}$  and  $V_{VCC\_OFF}$ , until HB voltage is below 6V and HV voltage is lower than HV OVP. SY59515 provides a constant internal current to pull down HB voltage through LX pin, so when MOSFET of SY59515 is turned on, there won't be large resonant current flowing through resonant capacitor. After the above two conditions are met, SY59515 will exit  $t_{STD}$  stage and enter into  $t_{STC2}$  stage.

$t_{STC2}$  is the  $C_{VCC}$  together with  $C_{VB}$  charging up section, once  $V_{VB}$  reaches  $V_{VB\_ON}$ , internal MOSFET of SY59515 is turned off, switching control starts to work and HV pin stops to provide charge current.  $t_{STO}$  is the output voltage building up section,  $V_{VCC}$  and  $V_{VB}$  will be pulled down by internal consumption current until the auxiliary winding of LLC transformer can supply enough energy to maintain  $V_{VCC}$  above  $V_{VCC\_OFF}$ .

Design of HV pin resistor  $R_{HV\_EXT}$ ,  $C_{VCC}$  and  $C_{VB}$  is not strict, below are some suggestions:

- Use  $R_{HV\_EXT}$  smaller than 200kohms, resistance of  $R_{HV\_EXT}$  will influence E-cap over voltage protection (HV OVP).
- Use  $C_{VCC}$  larger than 470nF, use  $C_{VB}$  larger than 100nF, there no need to use very large  $C_{VCC}$  or  $C_{VB}$  capacitor, suggest using 2uF  $C_{VCC}$  and 1uF  $C_{VB}$ .
- If  $C_{VCC}$  and  $C_{VB}$  are not big enough to build up output voltage at one time, increase  $C_{VCC}$  and  $C_{VB}$ , or check whether the output E-cap is too large.

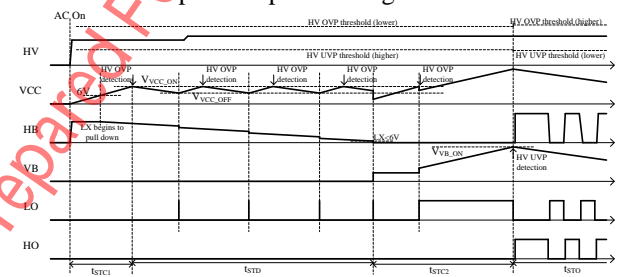


Fig.3 Start up Process of SY59516 and SY59515

After  $V_{VB\_ON}$  and high side MOSFET is turned on, soft start up function works, it prevents resonant current from being too high at start up. Switching frequency is fixed at maximum switching frequency  $f_{SW\_MAX}$  during the first few resonant periods.

### Primary side LED current regulation (PSR)

The PSR principle is as follows: LED current is estimated by sensing primary side resonant current, sampling resistor is put between HB and inductor or transformer, HB is the source of internal MOSFET of SY59516 and the drain of internal MOSFET of SY59515, so both current flowing into HB and current flowing out of HB can be detected.

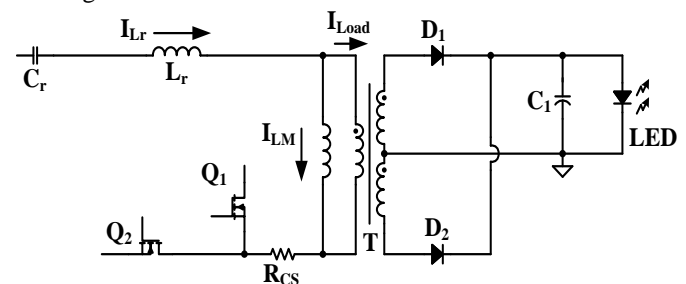


Fig.4 PSR principle of SY59516

The output current program is shown as below:

$$I_{LED} \approx \frac{V_{REF} \times N_{PS}}{R_{CS}}$$

So  $I_{LED}$  can be programmed by CS pin resistor.

### Shut down

After AC supply or DC BUS is powered off, LLC still works for a while to consume the energy stored in input E-cap. During this time, auxiliary winding can still provide stable VCC voltage so SY59515 and SY59516 can continue with the internal working logic. Once HV pin voltage reaches E-cap under voltage protection (HV UVP), SY59515 will keep internal MOSFET off and SY59516 will turn off its internal MOSFET soon. Once high side and low side MOSFET are turned off,  $C_{VCC}$  and  $C_{VB}$  will discharge, discharge current of  $C_{VCC}$  is quiescent current of SY59515 and discharge current of  $C_{VB}$  is constant 6mA. Usually,  $V_{VB}$  reaches  $V_{VB\_OFF}$  earlier than  $V_{VCC}$  reaches  $V_{VCC\_OFF}$ . When  $V_{VB}$  reaches  $V_{VB\_OFF}$ , 6mA discharge current will be removed. When  $V_{VCC}$  reaches  $V_{VCC\_OFF}$ , SY59515 will restart and HV pin starts to provide charge current.

### Over current protection (OCP), Over temperature protection (OTP), Thermal fold back (TFB)

OCP: CS voltage reflects resonant current, when  $|V_{RCS}|$  reaches 500mV, SY59516 will force change the LX state and force switch the high side and low side MOSFET. Under normal parameter design, it's not easy to trigger OCP. OCP is also not common in other protections, such as OTP, OLP, and SLP. Under special conditions, such as resonant inductor fault or transformer fault, OCP can protect the system from overheating. OCP won't restart the system, it only increases the switching frequency, because the MOSFET is switched earlier.

TFB: When temperature is too high,  $V_{REF}$  will begin to drop, the specific curve is shown in Fig.5. When SY59516 reaches 149°C,  $V_{REF}$  begins to drop, as the temperature rises,  $V_{REF}$  goes down at a constant slope. When SY59516 reaches 155°C,  $V_{REF}$  drops to 50% of the rated value and if the temperature keeps rising,  $V_{REF}$  keeps constant and stops to drop.

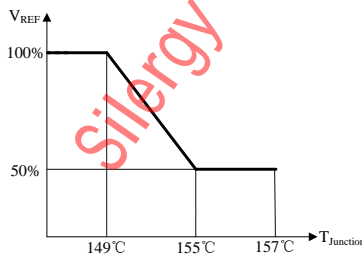


Fig.5 Thermal Fold Back Curve of SY59516

OTP: When SY59516 reaches 157°C, SY59516 will enter fault state, it will turn off high side MOSFET and

pull up LX, so low side MOSFET is turned off, too. At the same time, SY59516 begins to discharge by 6mA until  $V_{VB}$  reaches  $V_{VB\_OFF}$ . Later when  $V_{VCC}$  reaches  $V_{VCC\_OFF}$ , SY59515 begins to restart. After restart, SY59516 will recognize OTP signal after  $V_{VB\_ON}$ , so even if temperature is always too high, MOSFET won't switching and system's heat is very low, there is no risk of overheating.

## Magnetic Element Design

According to the design table, calculate the resonant inductor, resonant capacitor and boost capacitor. Left part of design table is one standard design with good performance, this topology has good normalized property, which means the resonant parameters is related to output current  $I_o$ , resonant frequency  $f_r$  and maximum output voltage  $V_{O\_MAX}$ .

### Inductor

System works in LC resonant condition, the peak value and RMS value of resonant current can be calculated:

$$I_{r\_peak} = 2 \times I_o / N_{ps}$$

$$I_{RMS} = \frac{I_{r\_peak}}{\sqrt{3}}$$

Usually select  $B_{max\_ind}$  between 0.2 and 0.3, so turn number of inductor can be calculated:

$$n_{ind} = \frac{I_{r\_peak} \times L_r}{A_{e\_ind} \times B_{max\_ind}}$$

It's recommended to use litz wire for lower temperature rise. Current density  $j_{ind}$  is selected at 8A/mm<sup>2</sup>, so the number of 0.1mm enameled wire  $n_{litz}$  can be calculated:

$$n_{litz} = \frac{4 \times I_{RMS}}{\pi \times j_{ind} \times 0.1^2}$$

### Transformer

RMS value of primary winding current is the same as inductor, so the wire diameters of primary and secondary winding are easy to get. Usually select  $B_{max\_trans}$  as 0.3, and the turn number of primary winding can be calculated:

$$n_{p\_trans} = \frac{V_{O\_MAX} \times n_{ps}}{4 \times f_r \times B_{max\_trans} \times A_{e\_trans}}$$

$$n_{s\_trans} = \frac{n_{s\_trans}}{n_{ps}}$$

The auxiliary winding should satisfy the following conditions:

$$V_{O\_OLP} + V_D = \frac{N_s}{N_{AUX}} \times (V_{VCC\_OVP} + V_D)$$

$$(V_{O\_MIN} + V_D) \times \frac{N_{AUX}}{N_s} - V_D > 13V$$

No air gap is required for transformer cores, large inductance of primary winding is needed, it's suggested that the ratio of inductance of primary winding and resonant inductor be larger than 3. If the ratio is small, it

needs to change the bobbin and core size of inductor or transformer.

### Magnetic integrated design

It's recommended to use magnetic integrated design for better efficiency and power density. In this design, leakage inductance of transformer primary winding is used as resonant inductor, so the key of magnetic integrated design is the control of leakage inductance. Fig.6 shows the structure of magnetic integrated transformer, primary and secondary windings are placed at left side and right side, respectively, between them is a big gap for larger leakage inductance. Leakage inductance mainly depends on the turn number of primary winding, bobbin size and the big gap in the middle. Red line represents the leakage inductance of primary winding, which is equivalent to the role of resonant inductor, and the green line represents the transformer excitation loop.

In magnetic integrated design, usually it's no need to consider the inductance ratio between primary winding and resonant inductor, because the bobbin size of transformer becomes larger than discrete design, the excitation inductance is much larger.

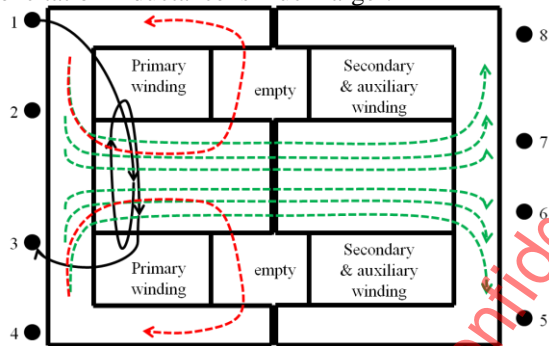
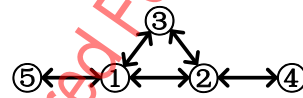


Fig.6 Structure of Magnetic Integrated Transformer

### Layout

- (a) Because of the charge pump structure, it's not necessary to put the input E-cap close to bridge rectifier. Make sure the loop composed of input E-cap, HV of SY59516, HB of SY59516, HB of SY59515 and GND of SY59515 to be as small as possible.
- (b) The circuit loop of CS sampling should be kept small.
- (c) The  $C_{VB}$  charge loop should be kept small,  $C_{VB}$  should be put near SY59516.
- (d) The  $C_{VCC}$  and  $N_{AUX}$  charging loop should be kept small,  $C_{VCC}$  should be put near SY59515.
- (e) Not recommend to put high voltage track under low voltage components, such as HV and LX.
- (f) Recommend to use a high voltage MLCC in parallel with input E-cap, recommend to connect the core of inductor to low frequency input line after filter.
- (g) The connection of ground is recommended as:



- Ground ①: ground of input E-cap
- Ground ②: ground of SY59515 and  $C_{VCC}$
- Ground ③: ground of external high voltage NP0 MLCC
- Ground ④: ground of auxiliary winding
- Ground ⑤: ground of bridge rectifier and  $C_{boost}$

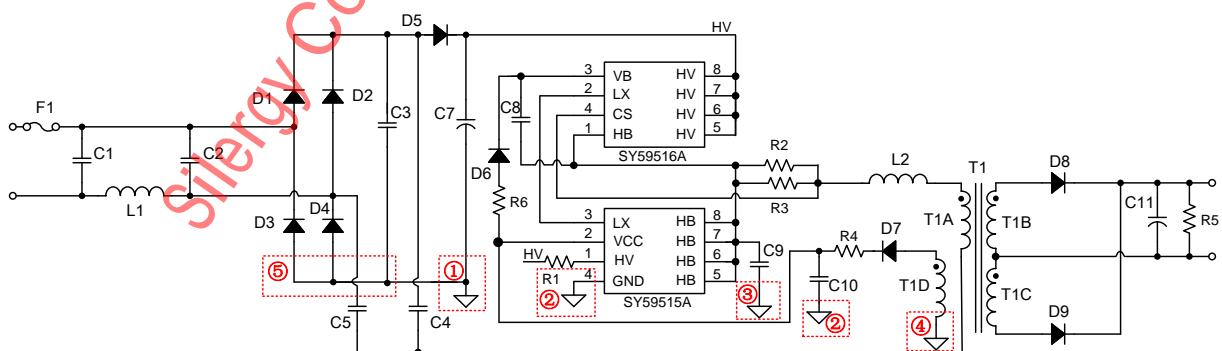


Fig.7 Ground Connection Recommended

## Design Example

Table 1 and table 2 show the key parameters of standard design in design table and parameters defined by the customer, respectively. The relationship between them is also provided.

Table 1 Key Parameters of Standard Design

System Conditions		
Maximum Output Voltage	$V_{O\_MAX\_S}$	42V
Output Current	$I_{O\_S}$	1A
Output Diode Drop	$V_{DF\_S}$	1.3V
Main Resonant Frequency	$f_{r\_S}$	52.5kHz
Key Parameters		
Turns Ratio	$N_{PS\_S}$	1.75
Sampling Resistor	$R_{CS\_S}$	0.26Ω
Resonant Inductor	$L_{r\_S}$	700uH
Main Resonant Capacitor	$C_{r\_S}$	27nF
Minor Resonant Capacitor	$C_{r2\_S}$	3.3nF
Boost Capacitor	$C_{boost\_S}$	15uF
Input E-cap	$C_{in\_S}$	15uF

Table 2 Parameters Defined by Customer

System Conditions		
Maximum Output Voltage	$V_{O\_MAX\_C}$	40V
Output Current	$I_{O\_C}$	0.8A
Output Diode Drop	$V_{DF\_C}$	1.3V
Main Resonant Frequency	$f_{r\_C}$	70kHz
Key Parameters		
Turns Ratio	$N_{PS\_C}$	1.83
Sampling Resistor	$R_{CS\_C}$	0.34Ω
Resonant Inductor	$L_{r\_C}$	689uH
Main Resonant Capacitor	$C_{r\_C}$	15.4nF
Minor Resonant Capacitor	$C_{r2\_C}$	1.9nF
Boost Capacitor	$C_{boost\_C}$	8.6nF
Input E-cap	$C_{in\_C}$	11uF

$$N_{PS\_C} = N_{PS\_S} \times \frac{V_{O\_MAX\_S} + V_{DF\_S}}{V_{O\_MAX\_C} + V_{DF\_C}}$$

$$R_{CS\_C} = 0.15 \times \frac{N_{PS\_C}}{I_{O\_C}}$$

$$L_{r\_C} = L_{r\_S} \times \frac{V_{O\_MAX\_S} \times I_{O\_S} \times f_{r\_S}}{V_{O\_MAX\_C} \times I_{O\_C} \times f_{r\_C}}$$

$$C_{r\_C} = C_{r\_S} \times \frac{V_{O\_MAX\_C} \times I_{O\_C} \times f_{r\_S}}{V_{O\_MAX\_S} \times I_{O\_S} \times f_{r\_C}}$$

$$C_{r2\_C} = C_{r2\_S} \times \frac{V_{O\_MAX\_C} \times I_{O\_C} \times f_{r\_S}}{V_{O\_MAX\_S} \times I_{O\_S} \times f_{r\_C}}$$

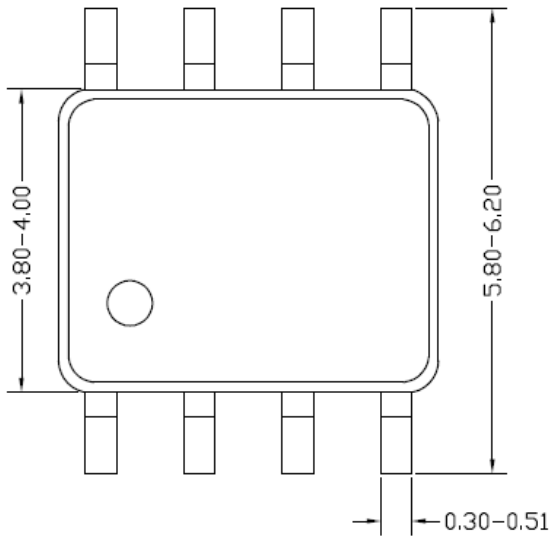
$$C_{boost\_C} = C_{boost\_S} \times \frac{V_{O\_MAX\_C} \times I_{O\_C} \times f_{r\_S}}{V_{O\_MAX\_S} \times I_{O\_S} \times f_{r\_C}}$$

$$C_{in\_C} = C_{in\_S} \times \frac{V_{O\_MAX\_C} \times I_{O\_C}}{V_{O\_MAX\_S} \times I_{O\_S}}$$

$V_{O\_MAX\_C}$ ,  $I_{O\_C}$ ,  $V_{DF\_C}$  and  $f_{r\_C}$  are defined by customer, and other key parameters will be calculated according to the above normalization formula.



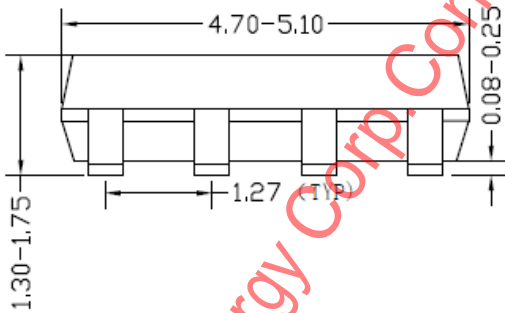
## S08 Package outline & PCB layout design



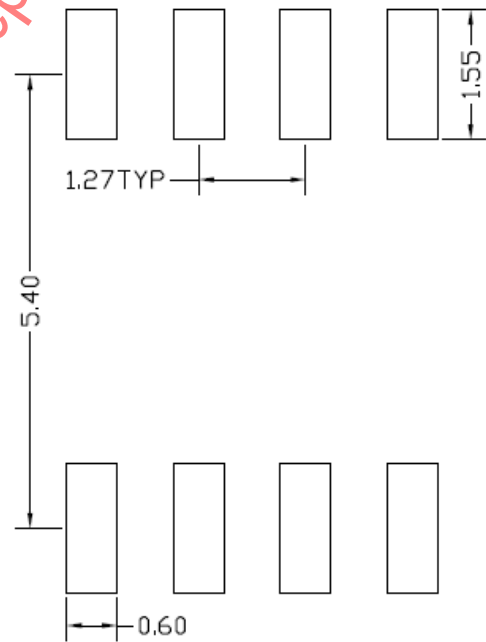
Top view



Side view



Front view



Recommended Pad Layout  
(Reference only)

**Notes:** All dimension in millimeter and exclude mold flash & metal burr.

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## Revision History

The revision history provided is for informational purpose only and is believed to be accurate, however, not warranted. Please make sure that you have the latest revision.

<b>Date</b>	<b>Revision</b>	<b>Change</b>
December 28,2021	Revision 0.9	Initial Release

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